International TOR Rectifier

30CPH06

Hyperfast Rectifier

Features

- · Hyperfastfast Recovery Time
- Low Forward Voltage Drop
- · Low Leakage Current
- 175°C Operating Junction Temperature

 t_{rr} = 40ns $I_{F(AV)}$ = 30Amp V_R = 600V

Description/ Applications

State of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, Hyperfast recover time, and soft recovery.

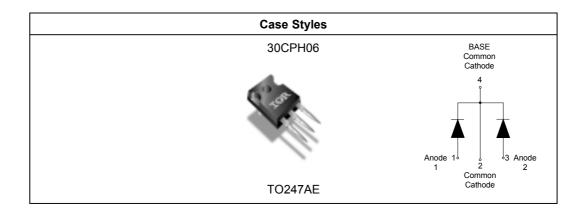
The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

The IR extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

	Parameters	Max	Units
V _{RRM}	Peak Repetitive Peak Reverse Voltage	600	V
I _{F(AV)}	Average Rectified Forward Current	30	Α
I _{FSM}	Non Repetitive Peak Surge Current	325	
I _{FM}	Peak Repetitive Forward Current	70	
T _J , T _{STG}	Operating Junction and Storage Temperatures	- 65 to 175	°C



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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Conditions		
V_{BR}, V_r	Breakdown Voltage, Blocking Voltage	600	-	-	V	Ι _R = 100μΑ		
V_{F}	Forward Voltage	-	-	2.3	V	I _F = 30A, T _J = 25°C		
		-	-	1.7	V	I _F = 30A, T _J = 150°C		
I _R	Reverse Leakage Current	-	-	250	μA	V _R = V _R Rated		
		-	-	1.0	mA	T _J = 150°C, V _R = V _R Rated		
Ст	Junction Capacitance	-	-	-	pF	V _R = 600V		
Ls	Series Inductance	-	-	-	nΗ	Measured lead to lead 5mm from package body		

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameters	Min	Тур	Max	Units	Test Conditions		
t _{rr}	Reverse Recovery Time	-	-	40	ns	$I_F = 1.0A$, $di_F/dt = 50A/\mu s$, $V_R = 30V$		
		-	-	-		$I_F = 30A$, $di_F/dt = 2$	200A/µs, V _R = 200V	
		-	-	-		T _J = 25°C	I _F = 30A	
			-	-		T _J = 125°C	V _R = 200V	
I _{RRM}	Peak Recovery Current	-	-	-	Α	T _J = 25°C	di _F /dt = 200A/µs	
		-	-	-		T _J = 125°C		
Qrr	Reverse Recovery Charge	-	-	100	nC	T _J = 25°C		
		-	-	-		T _J = 125°C		

Thermal - Mechanical Characteristics

	Parameters		Min	Тур	Max	Units
TJ	Max. Junction Temperature Range		-	-	- 65 to 175	°C
T _{Stg}	Max. Storage Temperature Range		-	-	- 65 to 175	
R _{thJC}	Thermal Resistance, Junction to Case	Per Leg	-	-	1.2	°C/W
R _{thJA} ^①	Thermal Resistance, Junction to Ambient	Per Leg	-	-	-	
$R_{thCS}^{^{\scriptsize{\textcircled{2}}}}$	Thermal Resistance, Case to Heatsink		-	-	-	
Wt	Weight		-	2.0	-	g
			-	0.07	-	(oz)
	Mounting Torque		6.0	-	12	Kg-cm
			5.0	-	10	lbf.in

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Typical Socket MountMounting Surface, Flat, Smooth and Greased